

DBP Organic Small Molecule as Hole Transport Layer in Perovskite based Photovoltaics

M. Ahmadpour, M. Madsen

Perovskite Solar Cells have recently attracting a lot of attention mainly due to their high power conversion efficiencies[1], which exceeds that of pure organic solar cells. In order to optimize the devices further, we here investigate the use of the electron donating organic semiconductor Tetraphenyldibenzoperiflanthen (DBP), which is typically used as a P-type active layer in pure organic solar cells due to its high absorption coefficient and hole mobility.

The property that makes DBP an ideal hole transport layer for mixed Perovskite solar cells lies on its energy band-diagram alignment to transport holes to the anode. In contrast to its low electron mobility, DBP shows promising results for hole extraction when fabricated at specific thicknesses and temperatures, which is due to its relatively high mobility for holes.[2] The combination of DBP/MoO₃ layer as hole transport layer further increases charge extraction of holes at the interface of DBP and MoO₃, and the improved recombination of electrons and holes at this interface increase the current production in the devices. [3] In this work, we demonstrate that optimization of the DBP and MoO₃ layers, especially in terms of layer thicknesses, has a strong impact on the devices performances, as characterized under standard 1 Sun conditions. The work has potential for improving further the device performance of Perovskite based devices.

- [1] S. Kazim, M. K. Nazeeruddin, M. Grätzel, and S. Ahmad, "Perovskite as light harvester: A game changer in photovoltaics," *Angew. Chemie - Int. Ed.*, vol. 53, no. 11, pp. 2812–2824, 2014.
- [2] S. Galindo, M. Ahmadpour, L. G. Gerling, A. Marsal, C. Voz, R. Alcubilla, and J. Puigdollers, "Influence of the density of states on the open-circuit voltage in small-molecule solar cells," *Org. Electron. physics, Mater. Appl.*, vol. 15, no. 10, pp. 2553–2560, 2014.
- [3] K. Kanai, K. Koizumi, S. Ouchi, Y. Tsukamoto, K. Sakanoue, Y. Ouchi, and K. Seki, "Electronic structure of anode interface with molybdenum oxide buffer layer," *Org. Electron. physics, Mater. Appl.*, vol. 11, no. 2, pp. 188–194, 2010.